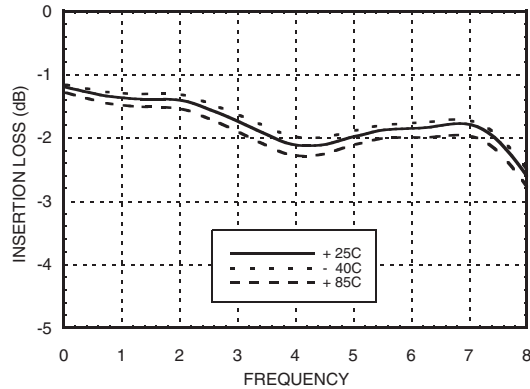
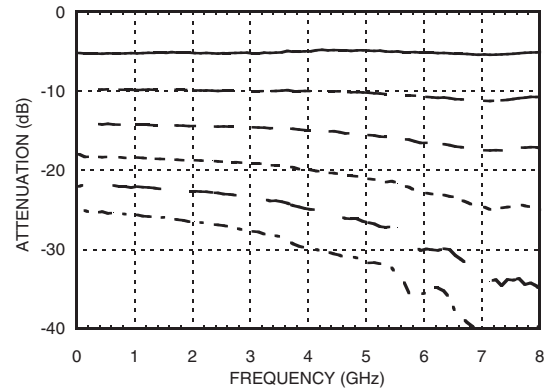


**GaAs MMIC HERMETIC SMT VOLTAGE-
VARIABLE ATTENUATOR, DC - 8 GHz**

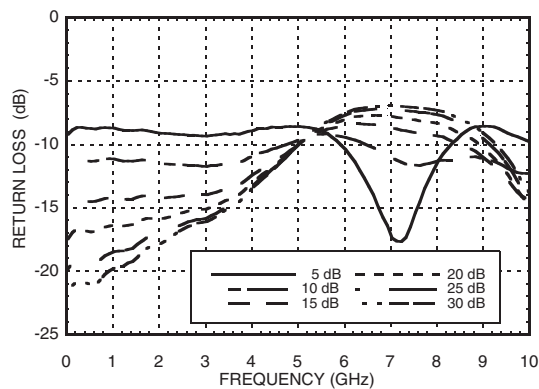
Insertion Loss vs. Temperature



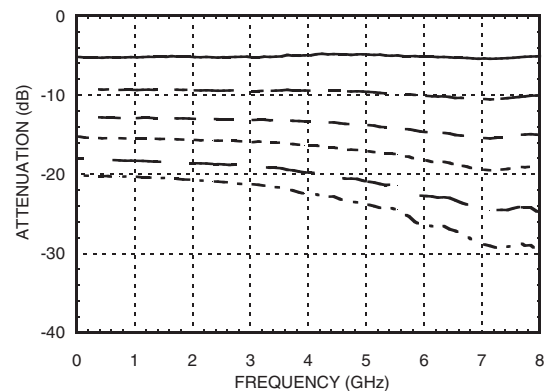
**Relative Attenuation, Control Voltage
Optimized for 4 GHz Operation**



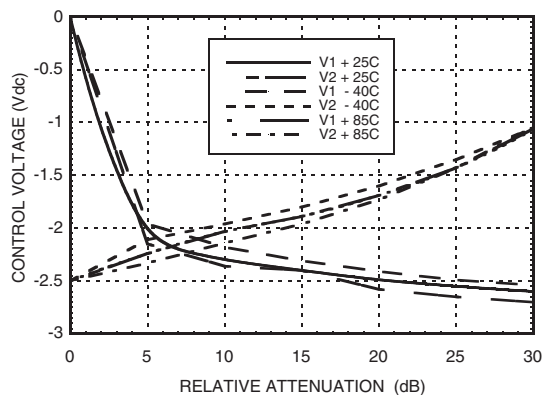
Return Loss vs. Attenuation



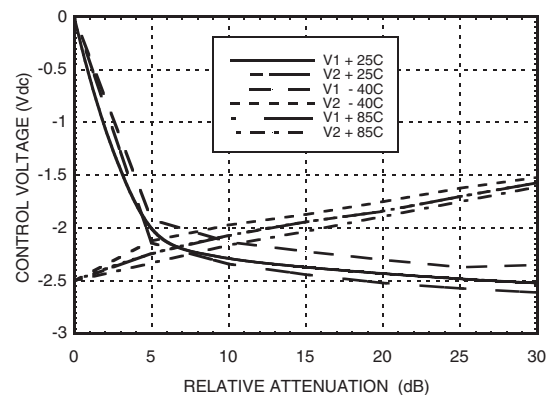
**Relative Attenuation, Control Voltage
Optimized for 8 GHz Operation**



**Relative Attenuation vs.
Control Voltage @ 4 GHz**



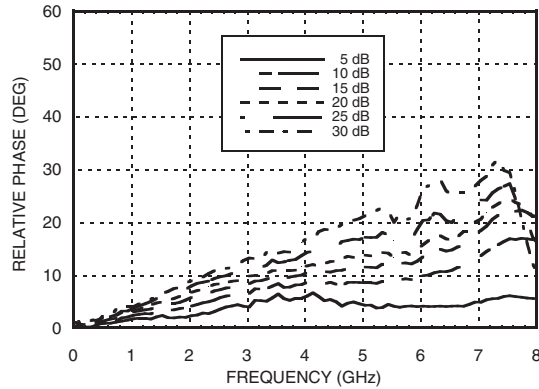
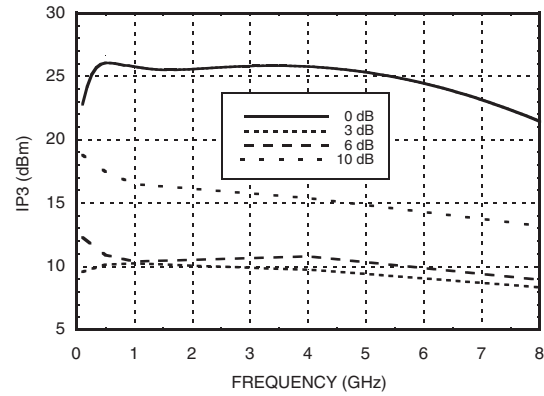
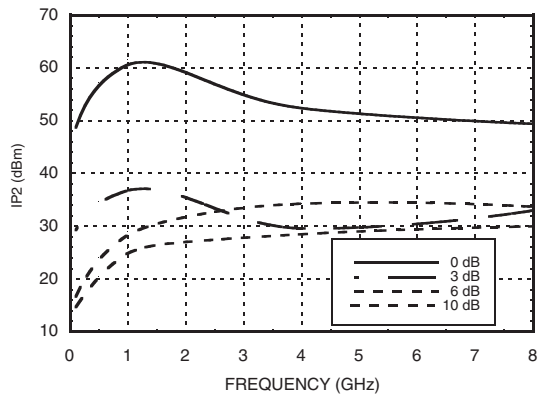
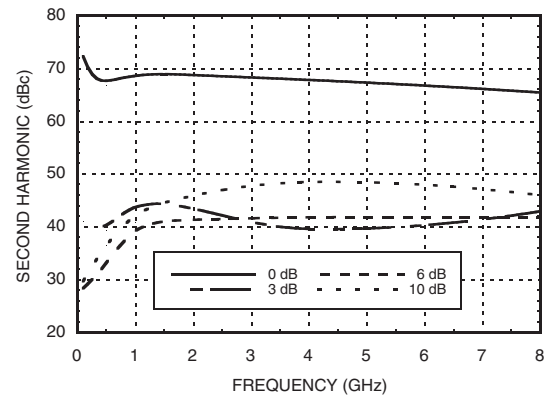
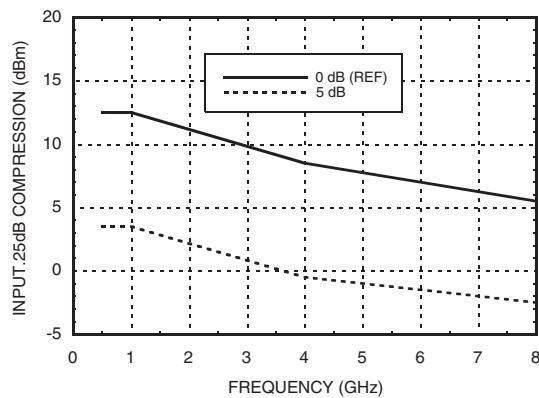
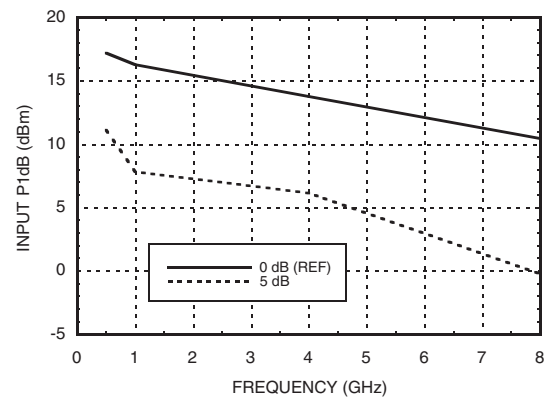
**Relative Attenuation vs.
Control Voltage @ 8 GHz**



GaAs MMIC HERMETIC SMT VOLTAGE-VARIABLE ATTENUATOR, DC - 8 GHz

5

ATTENUATORS - SMT

Relative Phase

Input Third Order Intercept vs. Attenuation*

Input Second Order Intercept vs. Attenuation*

Second Harmonic vs. Attenuation

0.25 dB Compression vs. Attenuation

1 dB Compression vs. Attenuation


*Two-tone input power = -8 dBm each tone.

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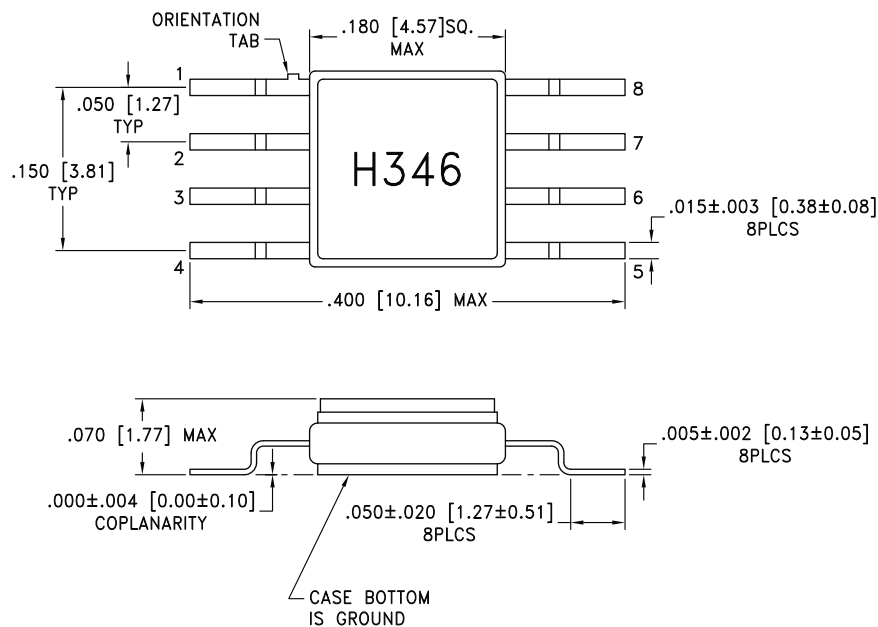
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**GaAs MMIC HERMETIC SMT VOLTAGE-
VARIABLE ATTENUATOR, DC - 8 GHz**
Absolute Maximum Ratings

RF Input Power	+18 dBm
Control Voltage Range	+1 to -5V
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A




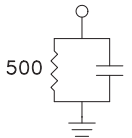
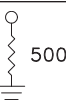
**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Outline Drawing

NOTES:

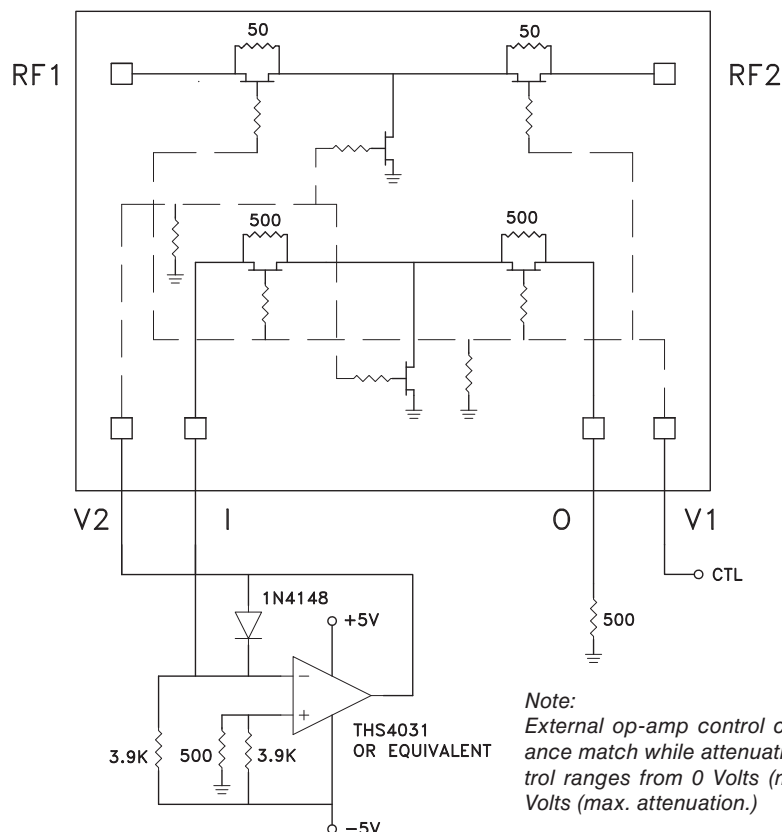
1. PACKAGE MATERIAL: ALUMINA LOADED BOROSILICATE GLASS.
2. LEAD, BASE, COVER MATERIAL: KOVAR™ (#7052 CORNING).
3. PLATING: ELECTROLYTIC GOLD 50 MICROINCHES MIN., OVER ELECTROLYTIC NICKEL 50 MICROINCHES MIN.
4. DIMENSIONS ARE IN INCHES [MILLIMETERS].
5. TOLERANCES: ±.005 [0.13] UNLESS OTHERWISE SPECIFIED.
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

GaAs MMIC HERMETIC SMT VOLTAGE- VARIABLE ATTENUATOR, DC - 8 GHz

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 8	RF1, RF2	This pin is DC coupled and matched to 50 Ohm. Blocking capacitors are required if RF line potential is not equal to 0V.	
2, 7	GND	This pin must be DC grounded.	
3, 6	V2, V1	Control Input (Master).	
4	I	Control Input (Slave).	
5	O	This pin must have an external 500 Ohm resistor to ground.	

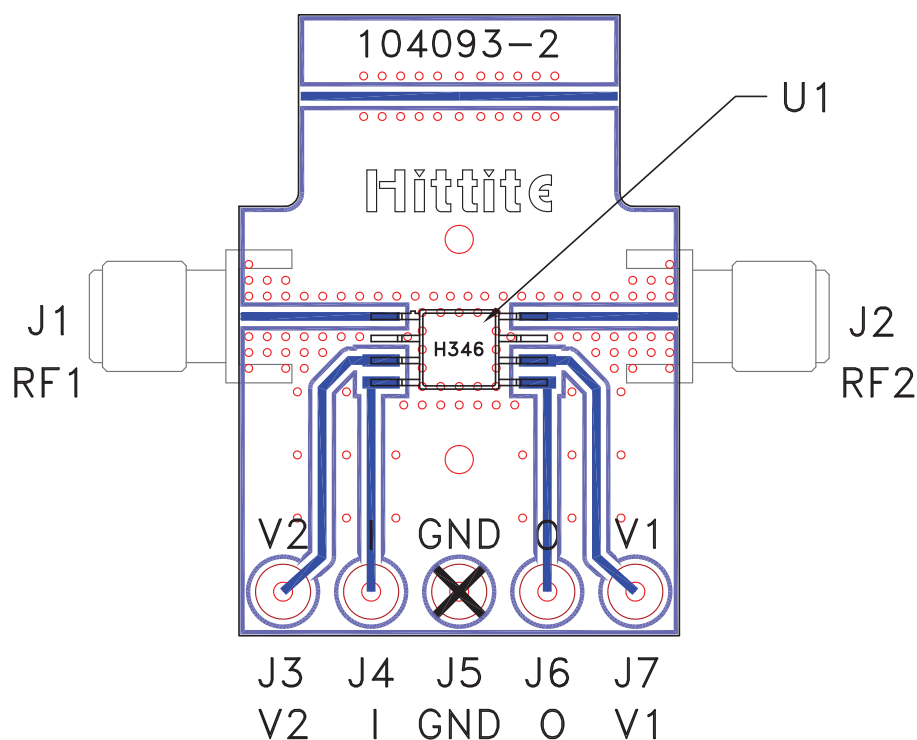
Single-Line Control Driver



Note:
External op-amp control circuit maintains impedance match while attenuation is varied. Input control ranges from 0 Volts (min. attenuation) to -2.5 Volts (max. attenuation.)

**GaAs MMIC HERMETIC SMT VOLTAGE-
VARIABLE ATTENUATOR, DC - 8 GHz**

Evaluation PCB



List of Materials for Evaluation PCB 104095 [1]

Item	Description
J1 - J2	PCB Mount SMA RF Connector
J3 - J7	DC PIN
U1	HMC346G8
PCB [2]	104093-2 Eval Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF ports should be 50 ohm impedance and the package ground leads and package bottom should be connected directly to the PCB RF ground plane, similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.